

## 4-8 GHz Broadband Low Noise Amplifier

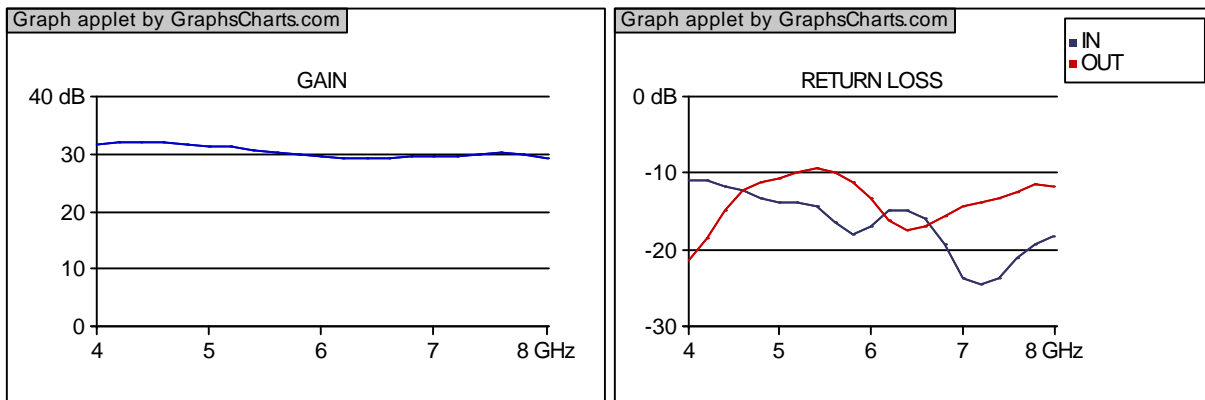
### Features:

- Thin Film Hybrid MIC Process
- Field Replaceable SMA Connectors
- DC Reverse Bias Protection

### Electrical Performance

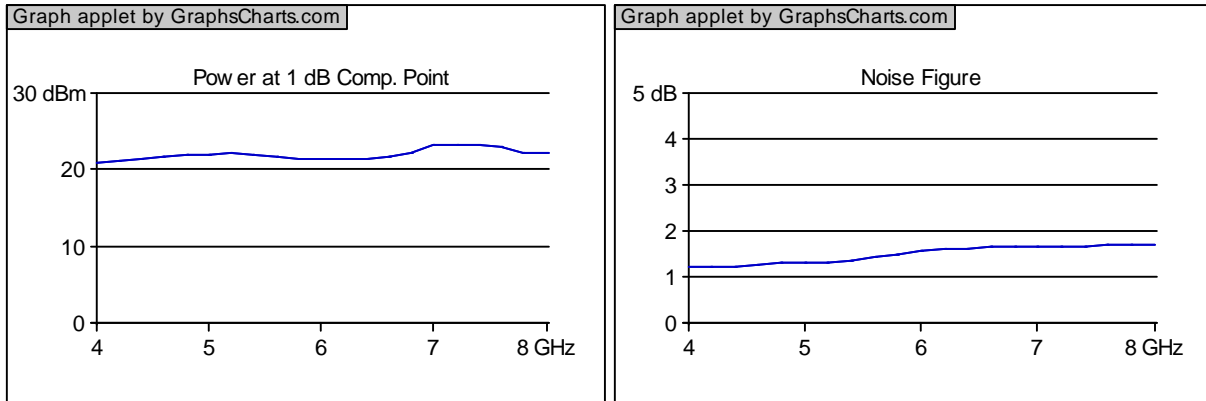
Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	4		8	GHz	
Gain	28			dB	
Gain Flatness			1.5	dB(+/-)	
VSWR Input			2.0		
VSWR Output			2.1		
Power @ 1dB Gain Compression Point	20			dBm	
Noise Figure			2	dB	
DC Supply Voltage	10	15	17	V	
Supplied Current			180	mA	

### Typical Test Data

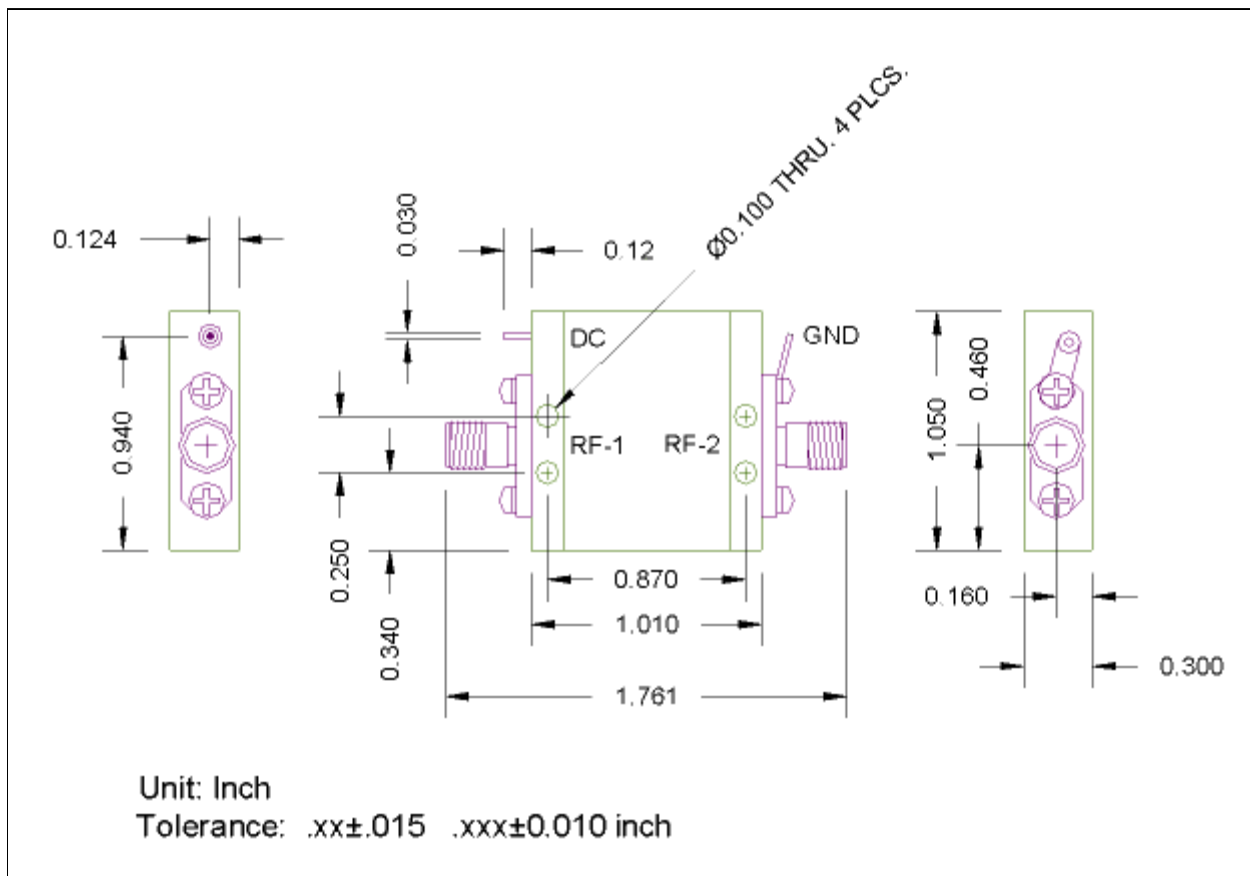


Updated: 12/2/2007

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### Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
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RF-1	SMA-F	1 IN	I	RF INPUT SIGNAL
RF-2	SMA-F	1 OUT	O	RF OUTPUT SIGNAL
DC	EMI Filter	1 + 12 V	I	DC INPUT (+10 TO +17 V)
GND	GROUND LUG	1 GND	O	GROUND

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